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FPF2116 IntelliMAX[™] Advanced Load Management Products

Features

- 1.8 to 5.5V Input Voltage Range
- Controlled Turn-On
- 200mA Current Limit
- Undervoltage Lockout
- Thermal Shutdown
- <2µA Shutdown Current</p>
- Auto Restart
- Fast Current limit Response Time
- 3µs to Moderate Over Currents
- 20ns to Hard Shorts
- Fault Blanking
- Reverse Current Blocking
- RoHS Compliant

Applications

- PDAs
- Cell Phones
- GPS Devices
- MP3 Players
- Digital Cameras
- Peripheral Ports
- Hot Swap Supplies

Typical Application Circuit

VIN VOUT FPF2116 OFF ON FLAGB GND FLAGB

Ordering Information

Part	Current Limit [mA]	Current Limit Blanking Time [ms]	Auto-Restart Time [ms]	ON Pin Activity	Top Mark
FPF2116	200	30	480	Active HI	2116



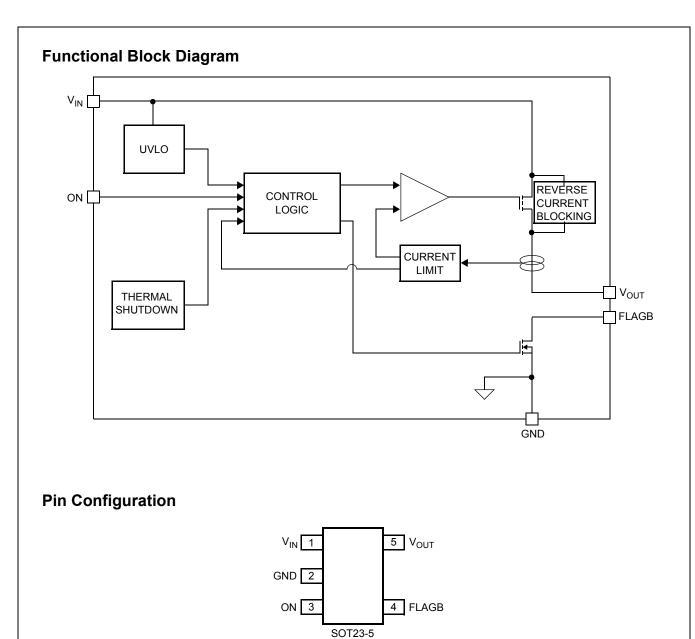
General Description

The FPF2116 is a load switch which provides full protection to systems and loads which may encounter large current conditions. This device contains a 0.125Ω current-limited P-channel MOSFET which can operate over an input voltage range of 1.8-5.5V. Internally, current is prevented from flowing when the MOSFET is off and the output voltage is higher than the input voltage. Switch control is by a logic input (ON) capable of interfacing directly with low voltage control signals. The part contains thermal shutdown protection which shuts off the switch to prevent damage to the part when a continuous over-current condition causes excessive heating.

When the switch current reaches the current limit, the part operates in a constant-current mode to prohibit excessive currents from causing damage. If the constant current condition still persists after 30ms, the part will shut off the switch and pull the fault signal pin (FLAGB) low. An auto-restart feature will turn the switch on again after 480ms if the ON pin is still active. The minimum current limit is 200mA.

The part is available in a space-saving 5 pin SOT23 package.

August 2008



Pin Description

Pin	Name	Function
1	V _{IN}	Supply Input: Input to the power switch and the supply voltage for the IC
2	GND	Ground
3	ON	ON Control Input
4	FLAGB	Fault Output: Active LO, open drain output which indicates an over current supply, under voltage or over temperature state.
5	V _{OUT}	Switch Output: Output of the power switch

Absolute Maximum Ratings

Parameter	Min	Max	Unit	
V _{IN} , V _{OUT} , ON, FLAGB to GND	-0.3	6	V	
Power Dissipation @ $T_A = 25^{\circ}C$ (note 1)		667	mW	
Operating Junction Temperature	-40	125	°C	
Storage Temperature	-65	150	°C	
Thermal Resistance, Junction to Ambient		150	°C/W	
Electrostatic Discharge Protection	НВМ	4000		V
Electrostatic Discharge Protection	MM	400		V

Recommended Operating Range

Parameter	Min	Max	Unit
V _{IN}	1.8	5.5	V
Ambient Operating Temperature, T _A	-40	85	°C

Electrical Characteristics

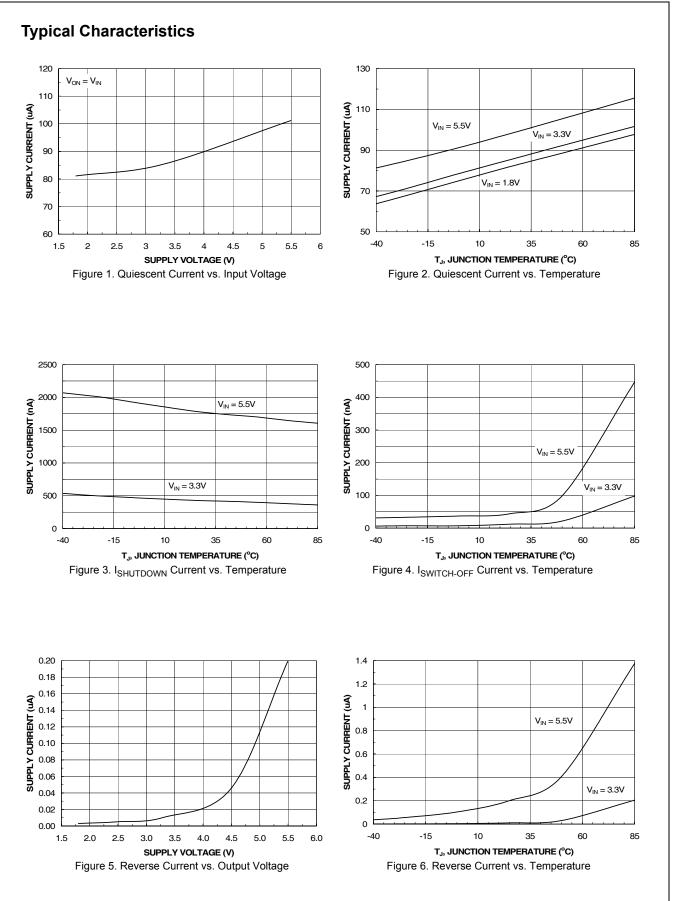
 V_{IN} = 1.8 to 5.5V, T_A = -40 to +85°C unless otherwise noted. Typical values are at V_{IN} = 3.3V and T_A = 25°C.

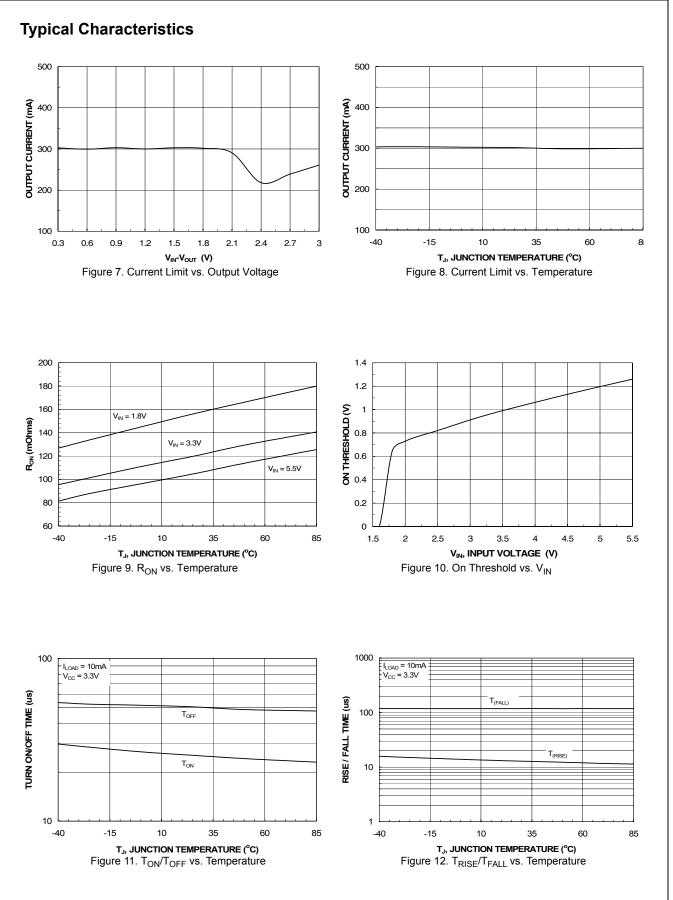
Parameter	Symbol	Conditions		lin	Тур	Max	Units
Basic Operation							
Operating Voltage	V _{IN}		1	1.8		5.5	V
Quiescent Current	1	V _{IN} = 1.	8 to 3.3V		95		
Quiescent Current	Ι _Q	$I_{OUT} = 0mA$ $V_{IN} = 3.$	3 to 5.5V		110	200	μA
V _{IN} Shutdown Current		V_{ON} = 0V, V_{IN} = 5.5V, V_{OUT} sho	ort to GND			2	μA
V _{OUT} Shutdown Current		V_{ON} = 0V, V_{OUT} = 5.5V, V_{IN} sho	rt to GND			2	μA
		V _{IN} = 3.3V, I _{OUT} = 50mA, T _A = 2	25°C		125	160	
On-Resistance	R _{ON}	V _{IN} = 3.3V, I _{OUT} = 50mA, T _A = 85°C			150	200	mΩ
		V _{IN} = 3.3V, I _{OUT} = 50mA, T _A = -	40°C to +85°C 6	65		200	
ON Input Logic High Voltage (ON)		V _{IN} = 1.8V		.75			v
	V_{H}	V _{IN} = 5.5V	1.	.30			v
	N	V _{IN} = 1.8V				0.5	v
ON Input Logic Low Voltage	V _{IL}	V _{IN} = 5.5V				1.0 V	v
ON Input Leakage		V _{ON} = V _{IN} or GND				1	μA
Off Switch Leakage	ISWOFF	$V_{ON} = 0V, V_{OUT} = 0V$				1	μA
FLAGB Output Logic Low Voltage		V _{IN} = 5V, I _{SINK} = 10mA			0.1	0.2	v
FLAGE Output Logic Low Voltage		V _{IN} = 1.8V, I _{SINK} = 10mA			0.15	0.3	v
FLAGB Output High Leakage Current		V _{IN} = 5V, Switch on				1	μA
Protections							
Current Limit	I _{LIM}	V _{IN} = 3.3V, V _{OUT} = 3.0V		200	300	400	mA
		Shutdown Threshold			140		
Thermal Shutdown		Return from Shutdown			130		°C
		Hysteresis			10		
Under Voltage Shutdown	UVLO	V _{IN} Increasing		1.5	1.6	1.7	V
Under Voltage Shutdown Hysteresis					50		mV

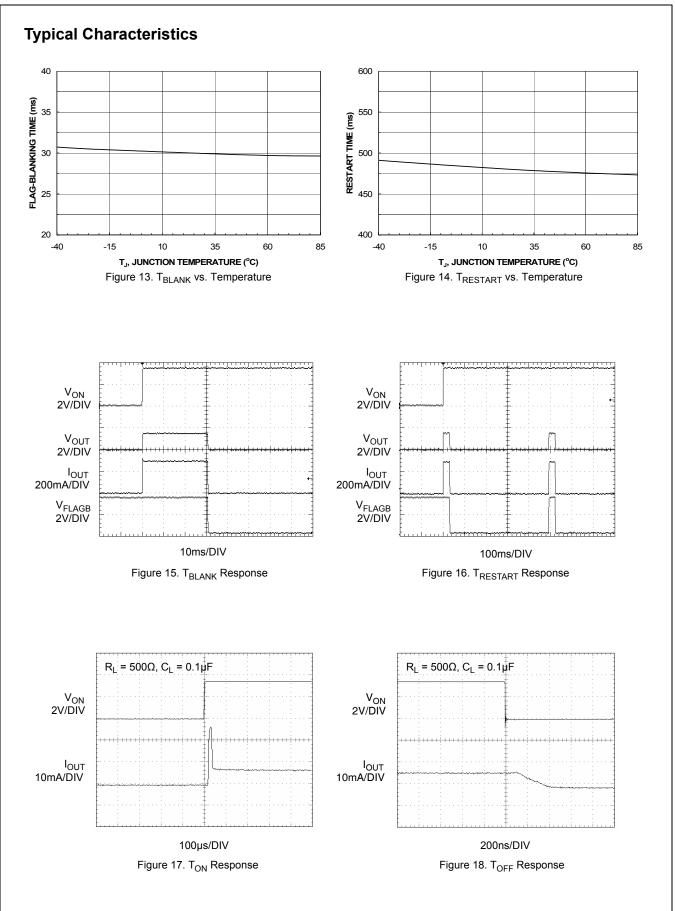
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Dynamic						•
Turn On Time	t _{ON}	$R_L = 500\Omega, C_L = 0.1\mu F$		25		μs
Turn Off Time	t _{OFF}	$R_L = 500\Omega, C_L = 0.1\mu F$		50		μs
V _{OUT} Rise Time	t _{RISE}	$R_L = 500\Omega, C_L = 0.1\mu F$		12		μs
V _{OUT} Fall Time	t _{FALL}	$R_L = 500\Omega, C_L = 0.1\mu F$		120		μs
Over Current Blanking Time	t _{BLANK}		15	30	60	ms
Auto-Restart Time	t _{RESTART}		240	480	960	ms
Short Circuit Response Time		V _{IN} = V _{ON} = 3.3V. Moderate Over-Current Condition.		3		μs
		V _{IN} = V _{ON} = 3.3V. Hard Short.		20		ns

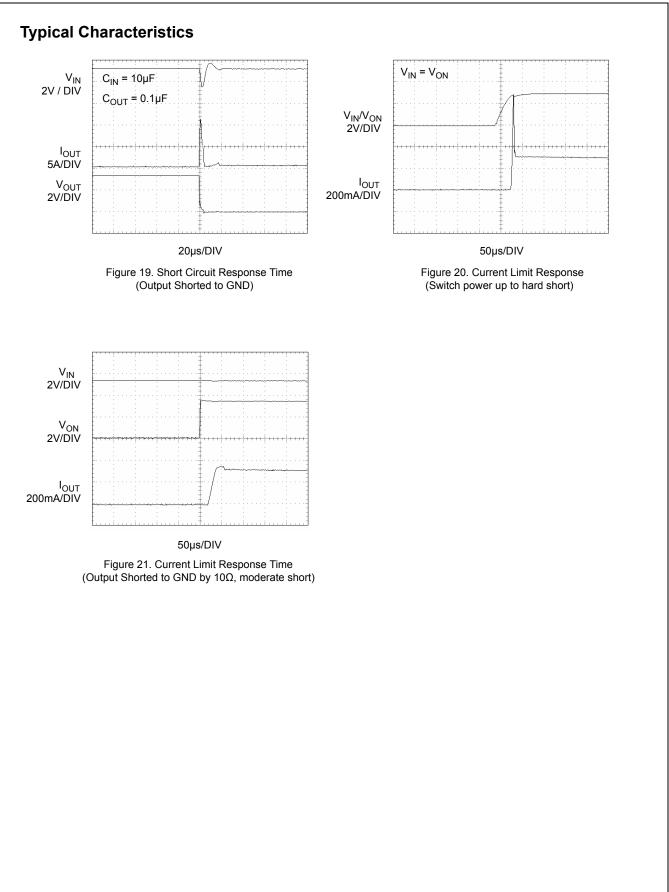
Note 1: Package power dissipation on 1square inch pad, 2 oz copper board.

Electrical Characteristics Cont.









Description of Operation

The FPF2116 is a current limited switch that protects systems and loads which can be damaged or disrupted by the application of high currents. The core of the device is a 0.125Ω P-channel MOSFET and a controller capable of functioning over a wide input operating range of 1.8-5.5V. The controller protects against system malfunctions through current limiting, undervoltage lockout and thermal shutdown. The current limit is preset for 200mA.

On/Off Control

The ON pin controls the state of the switch. Activating ON continuously holds the switch in the on state so long as there is no fault. An under-voltage on V_{IN} or a junction temperature in excess of 150°C overrides the ON control to turn off the switch. In addition, excessive current will cause the switch to turn off. The part has an Auto-Restart feature which will automatically turn the switch on again after 480 ms. ON is active HI and has a low threshold making it capable of interfacing with low voltage signals. When the MOSFET is off, the body diode is disabled so no current can flow through it.

Fault Reporting

Upon the detection of an over-current, an input under-voltage, or an over-temperature condition, the FLAGB signals the fault mode by immediately activating LO. The FLAGB goes LO at the end of the blanking time. It will remain LO during the fault and immediately returns HI at the end of the fault condition. FLAGB is an open-drain MOSFET which requires a pull-up resistor between V_{IN} and FLAGB. During shutdown, the pull-down on FLAGB is disabled to reduce current draw from the supply.

Current Limiting

The current limit ensures that the current through the switch doesn't exceed 400mA while not limiting at less than 200mA. The part has a blanking time of 30 ms, nominally, during which the switch will act as a constant current source. At the end of the blanking time, the switch will be turned-off and the FLAGB pin will activate to indicate that current limiting has occurred.

Under-Voltage Lockout

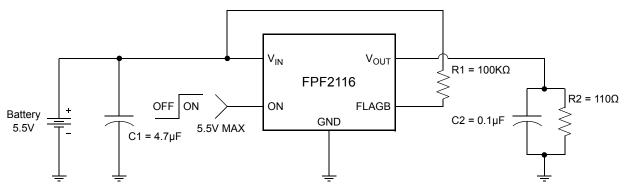
The under-voltage lockout turns-off the switch if the input voltage drops below the under-voltage lockout threshold. With the ON pin active the input voltage rising above the under-voltage lockout threshold will cause a controlled turn-on of the switch which limits current over-shoots.

Thermal Shutdown

The thermal shutdown protects the part from internally or externally generated excessive temperatures. During an overtemperature condition the FLAGB is activated and the switch is turned-off. The switch automatically turns-on again if temperature of the die drops below the threshold temperature.

Application Information

Typical Application



Input Capacitor

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns-on into a discharged load capacitor or a short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 4.7 μ F ceramic capacitor, C_{IN}, must be placed close to the V_{IN} pin. A higher value of C_{IN} can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

Output Capacitor

A 0.1uF capacitor C_{OUT} , should be placed between V_{OUT} and GND. This capacitor will prevent parasitic board inductances from forcing V_{OUT} below GND when the switch turns-off. The total output capacitance needs to be kept below a maximum value, $C_{OUT}(max)$, to prevent the part from registering an over-current condition and turning off the switch. The maximum output capacitance can be determined from the following formula,

$$C_{OUT}(max) = \frac{I_{LIM}(min) \times t_{BLANK}(min)}{V_{IN}}$$
(1)

Power Dissipation

During normal operation as a switch, the power dissipation is small and has little effect on the operating temperature of the part. The parts with the higher current limits will dissipate the most power and that will only be,

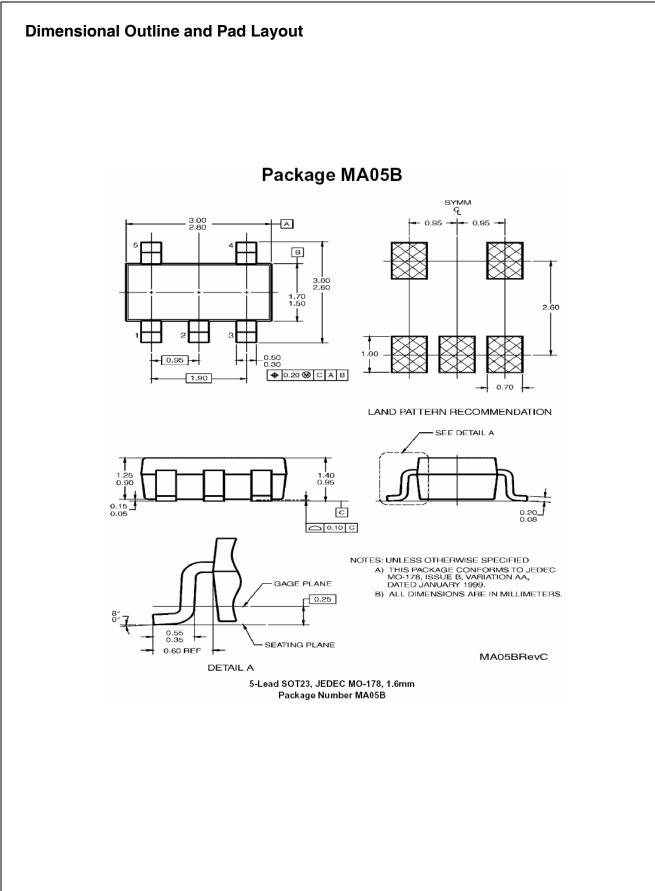
$$P = (I_{LIM})^{2} \times R_{DS} = (0.4)^{2} \times 0.125 = 20 \text{mW}$$
 (2)

When in current limit the maximum power dissipation will occur when the output is shorted to ground. The power dissipation will scale by the Auto-Restart Time, t_{RSTRT} , and the Over Current Blanking Time, t_{BLANK} , so that the maximum power dissipated is typically,

$$P(max) = \frac{t_{BLANK}}{t_{RETRY} + t_{BLANK}} \times V_{IN}(max) \times I_{LIM}(max)$$
$$= \frac{60}{60 + 960} \times 5.5 \times 0.4 = 130 \text{mW}$$
(3)

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for V_{IN} , V_{OUT} and GND will help minimize parasitic electrical effects along with minimizing the case to ambient thermal impedance.



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